

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

RECEIVED
CENTRAL FAX CENTER

OCT 14 2005

Serial No.:	10/709,776	Conf. No.:	3775
Filing Date:	05/27/2004	Art Unit:	2811
Applicant:	William G. America	Examiner:	IM, Junghwa M.
Title:	SEMICONDUCTOR DEVICE FORMED BY IN-SITU MODIFICATION OF DIELECTRIC LAYER AND RELATED METHODS	Docket No.:	FIS920040083US1 (IBMF-0058)

COMMISSIONER FOR PATENTS


DESTINATION FACSIMILE NUMBER: 571-273-8300

Transmitted herewith is: **Response to Restriction Requirement in 7 pages**
in the above identified application.

CERTIFICATION OF FACSIMILE TRANSMISSION

I hereby certify that this correspondence is being facsimile transmitted to the United States Patent and Trademark Office on the date shown below.

Linda T. Sagarese
(Person transmitting this correspondence)

 October 14, 2005
Signature Date

If you receive this correspondence in error or do not receive the entire transmission, please notify us at (518) 449-0044.

RECEIVED
CENTRAL FAX CENTER

OCT 14 2005

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re Application of: William G. America

Conf. No.: 3775

Serial No.: 10/709,776

Art Unit: 2811

Filed: 5/27/2004

Dkt. #: FIS920040083US1 (IBMF-0058)

Title: SEMICONDUCTOR DEVICE FORMED
BY IN-SITU MODIFICATION OF
DIELECTRIC LAYER AND RELATED
METHODS

Examiner: IM, Junghwa M

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

RESPONSE TO RESTRICTION REQUIREMENT

Sir:

I. INTRODUCTORY COMMENTS

This paper is being filed in response to the Restriction Requirement dated September 22, 2005. Applicant hereby provisionally elects Group I, claims 1-7, with traverse.